## USSN 09/900,662

## **AMENDMENTS OF CLAIMS**

- (Currently amended) A data storage device comprising an array of nanotubes as electron sources; and a phase-change storage layer proximate tips of the electron sources.
- 2. (Original) The device of claim 1, wherein the nanotubes are carbon-based.
- 3. (Original) The device of claim 1, wherein the nanotubes are boron nitride-based.
- 4. (Cancelled)
- (Original) The device of claim 1, wherein each nanotube electron source is elongated.
- 6. (Original) The device of claim 5, wherein the nanotubes have an aspect ratio greater than 10:1.
- 7. (Original) The device of claim 1, further comprising word and bit lines for addressing the nanotubes.
- 8. (Original) The device of claim 1, further comprising a micromover for positioning the array.

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- (Original) A data storage device comprising:
   an array of carbon-based nanotubes; and
   a phase-change storage layer proximate tips of the nanotubes.
- 10. (Original) A data storage device comprising:
  an array of boron nitride-based nanotubes; and
  a phase-change storage layer proximate tips of the nanotubes.

Claims 11-16 (Cancelled)